



40V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	Rds(on) Max	Ι _D T _C = +25°C
40V	1.0mΩ @ V _{GS} = 10V	225A

Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Thermally Efficient Package-Cooler Running Applications High Conversion Efficiency
- Low RDS(ON) Minimizes On State Losses
- <1.1mm Package Profile Ideal for Thin Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH4001SPSQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

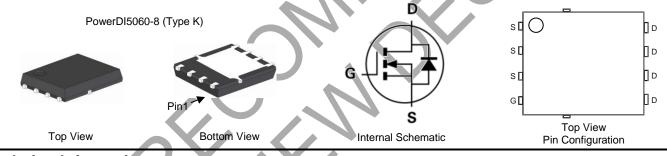
Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Engine Management Systems
- Body Control Electronics
- DC-DC Converters

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
 - Weight: 0.097 grams (Approximate)



Ordering Information (Note 4)

Part Number	Package	Packing		
Part Nulliber	Fackage	Qty.	Carrier	
DMTH4001SPSQ-13	PowerDI5060-8 (Type K)	2,500	Tape & Reel	

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



) | | = Manufacturer's Marking
TH4001SS = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 21 = 2021)
WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	40	V	
Gate-Source Voltage		Vgss	±20	V
Continuous Drain Current, V _{GS} = 10V (Note 6)	T _C = +25°C T _C = +100°C	ID	225 160	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I _{DM}	900	А
Continuous Body Diode Forward Current (Note 6)	Tc = +25°C	ls	200	А
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)	lsм	900	А	
Avalanche Current, L = 0.1mH		las	93.8	А
Avalanche Energy, L = 0.1mH		Eas	440	mJ

Thermal Characteristics

	Symbol	Value	Unit
T _A = +25°C	Po	3.1	W
	Reja	48	°C/W
Tc = +25°C	Po	187.5	W
	R _{θJC}	0.8	°C/W
	TJ, TSTG	-55 to +175	°C
		$T_A = +25^{\circ}C$ PD R_{0JA} $T_C = +25^{\circ}C$ P_D R_{0JC}	$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

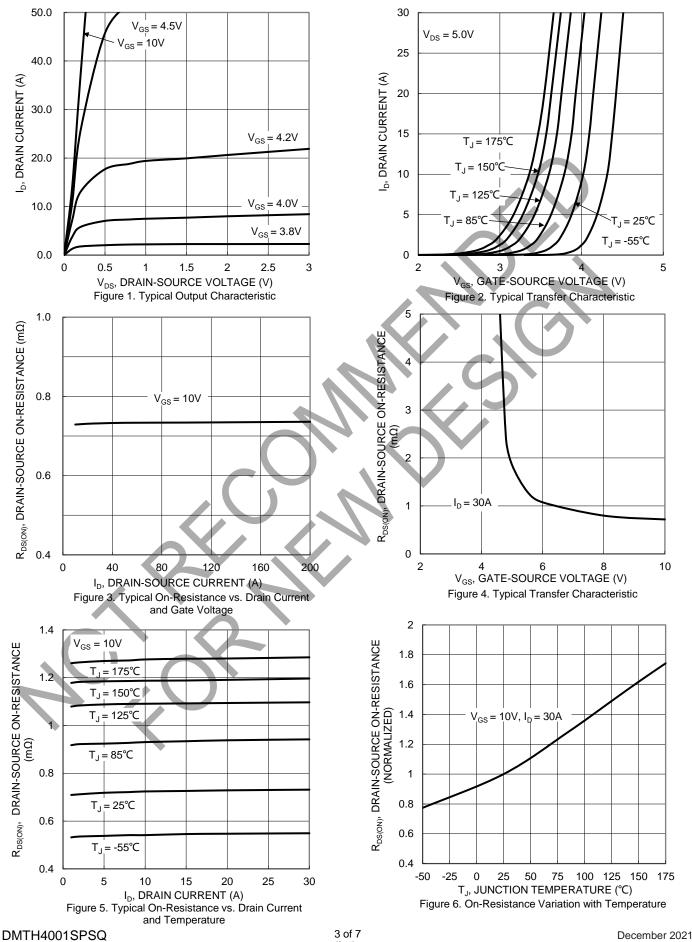
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Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)						1	
Drain-Source Breakdown Voltage	BVDSS	40		—	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS	_		1	μA	$V_{DS} = 32V, V_{GS} = 0V$	
Gate-Source Leakage	lgss	—	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	2	2.61	4	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	RDS(ON)	—	0.73	1.0	mΩ	V _{GS} = 10V, I _D = 30A	
Diode Forward Voltage	V _{SD}		0.7	1.3	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	-	10787	_			
Output Capacitance	Coss	-	3929	_	pF	$V_{DS} = 20V, V_{GS} = 0V,$ f = 1MHz	
Reverse Transfer Capacitance	Crss	~	156	—			
Gate Resistance	Rg	—	3.71	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	_	144	_		V _{DD} = 20V, I _D = 50A, V _{GS} = 10V	
Gate-Source Charge	Qgs	_	40	—	nC		
Gate-Drain Charge	Qgd	_	24	_			
Turn-On Delay Time	tD(ON)	_	11	—		$V_{DD} = 20V, V_{GS} = 10V,$ $I_D = 50A, R_g = 2.5\Omega$	
Turn-On Rise Time	t _R	_	44	—	20		
Turn-Off Delay Time	tD(OFF)	_	85	—	ns		
Turn-Off Fall Time	tF	_	38	—			
Reverse Recovery Time	trr	—	68	—	ns	1- 150 di/dt 1000/up	
Reverse Recovery Charge	Qrr	_	110	—	nC	−I _F = 15A, di/dt = 100A/μs	

 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
 Thermal resistance from junction to soldering point (on the exposed drain pad). Notes:

Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.



DMTH4001SPSQ

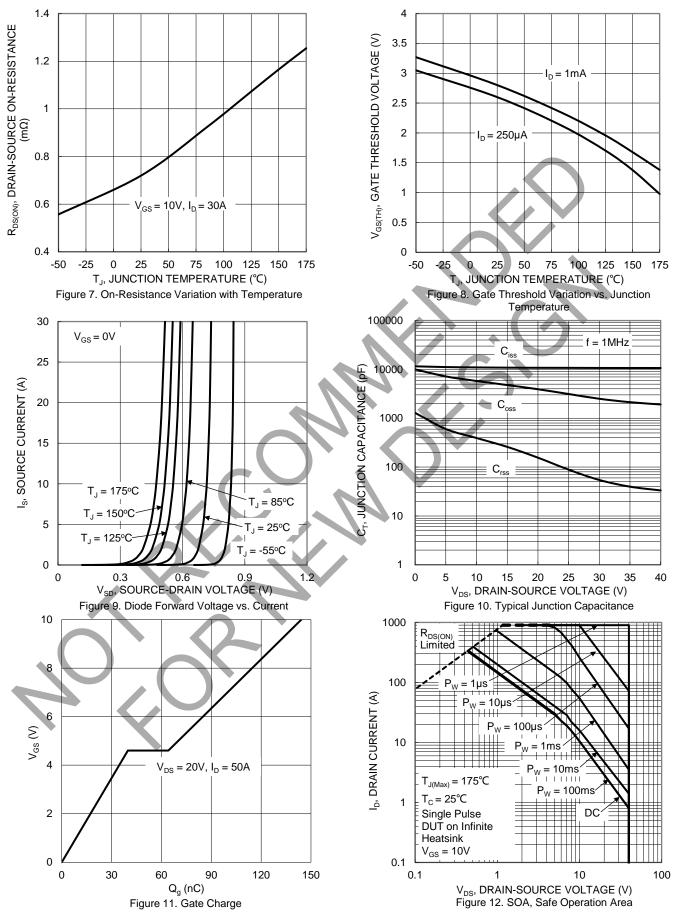


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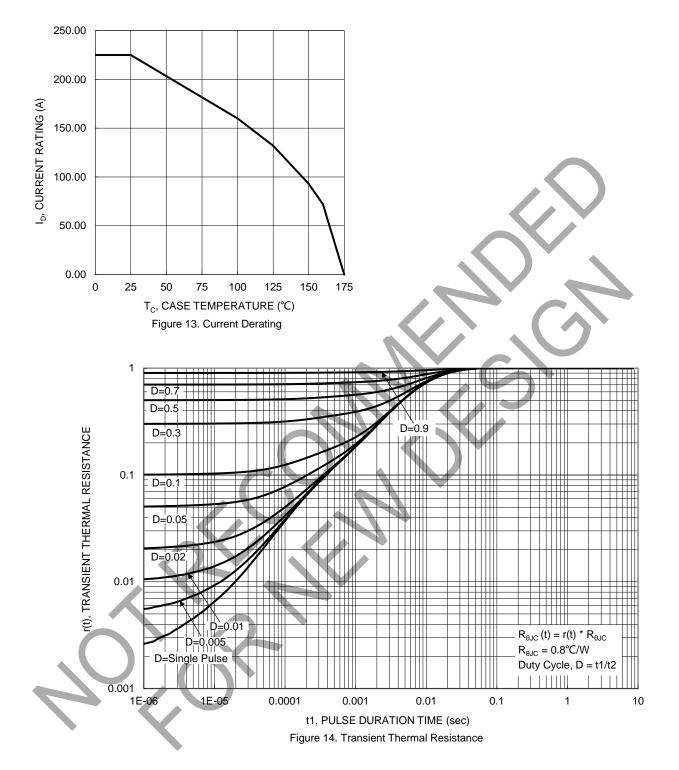


DMTH4001SPSQ



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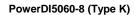


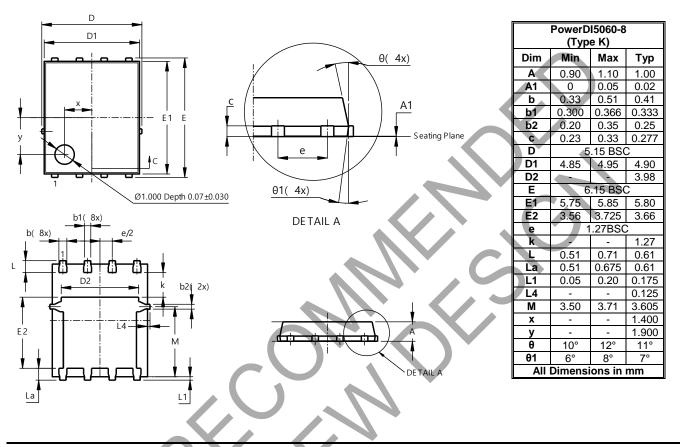




Package Outline Dimensions

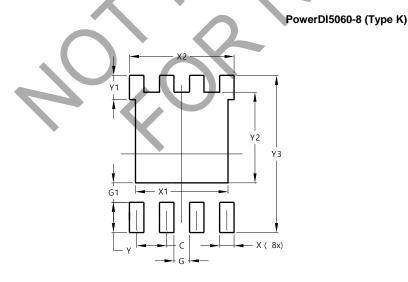
Please see http://www.diodes.com/package-outlines.html for the latest version.





Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Value Dimensions (in mm) С 1.270 G 0.660 G1 0.820 Х 0.610 X1 3.910 Х2 4.420 Υ 1.270 Y1 1.020 Y2 3.810 Y3 6.610



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